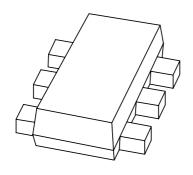
DISCRETE SEMICONDUCTORS

DATA SHEET



PEMZ1 NPN/PNP general purpose transistors

Product specification Supersedes data of 2001 Sep 25 2001 Nov 07





NPN/PNP general purpose transistors

PEMZ1

FEATURES

- 300 mW total power dissipation
- Very small 1.6 × 1.2 mm ultra thin package
- Self alignment during soldering due to straight leads
- Replaces two SC-75/SC-89 packaged transistors on same PCB area
- · Reduced required PCB area
- · Reduced pick and place costs.

APPLICATIONS

- · General purpose switching and amplification
- Complementary MOSFET driver for switch mode power supply
- · Complementary driver for audio amplifiers.

DESCRIPTION

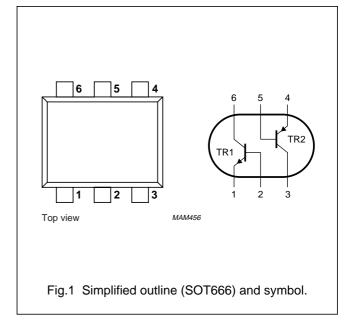
NPN/PNP transistor pair in a SOT666 plastic package.

MARKING

TYPE NUMBER	MARKING CODE		
PEMZ1	FZ		

PINNING

PIN	DESCRIPTION		
1, 4	emitter	TR1; TR2	
2, 5	base	TR1; TR2	
6, 3	collector	TR1; TR2	



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT	
Per transis	Per transistor; for the PNP transistor with negative polarity					
V _{CBO}	collector-base voltage	open emitter	_	50	V	
V _{CEO}	collector-emitter voltage	open base	_	40	V	
V _{EBO}	emitter-base voltage	open collector	_	5	V	
I _C	collector current (DC)		_	100	mA	
I _{CM}	peak collector current		_	200	mA	
I _{BM}	peak base current		_	200	mA	
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	200	mW	
T _{stg}	storage temperature		-65	+150	°C	
Tj	junction temperature		_	150	°C	
T _{amb}	operating ambient temperature		-65	+150	°C	
Per device	Per device					
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	300	mW	

Note

1. Transistor mounted on an FR4 printed-circuit board.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	notes 1 and 2	416	K/W

Notes

- 1. Transistor mounted on an FR4 printed-circuit board.
- 2. The only recommended soldering method is reflow soldering.

CHARACTERISTICS

 T_{amb} = 25 °C; unless otherwise specified.

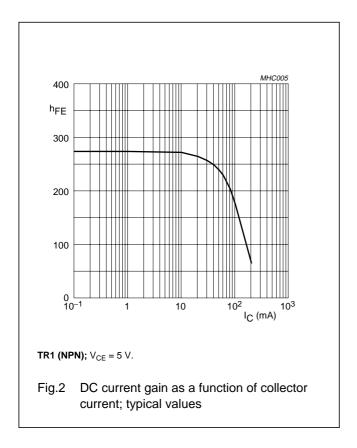
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Per transis	Per transistor; for the PNP transistor with negative polarity					
I _{CBO}	collector-base cut-off current	V _{CB} = 30 V; I _E = 0	_	_	100	nA
		V _{CB} = 30 V; I _E = 0; T _j = 150 °C	_	_	10	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 4 V; I _C = 0	_	_	100	nA
h _{FE}	DC current gain	V _{CE} = 6 V; I _C = 1 mA	120	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 50 \text{ mA}$; $I_B = 5.0 \text{ mA}$; note 1	_	_	200	mV
f _T	transition frequency	I _C = 2 mA; V _{CE} = 12 V; f = 100 MHz	100	_	_	MHz
C _c	collector capacitance	I _E = i _e = 0; V _{CB} = 12 V; f = 1 MHz				
	TR1 (NPN)		_	-	1.5	pF
	TR2 (PNP)		_	-	2.2	pF

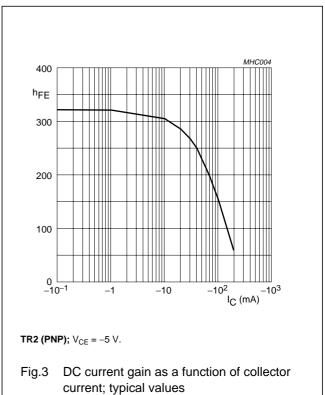
Note

1. Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

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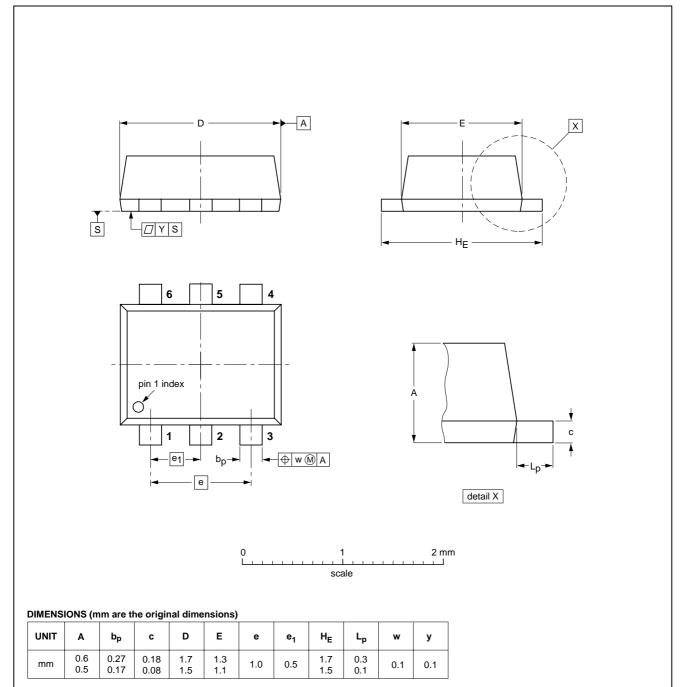
NPN/PNP general purpose transistors

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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT666



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT666						-01-01-04 01-08-27

NPN/PNP general purpose transistors

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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Notes

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NOTES

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